

Date: - 28th August, 2012

Data Sheet Issue:- A2

Provisional Data

Phase Control Thyristor Types N3790T#240 to N3790T#280

Development Type No.: NX223TJ280

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{DRM}	Repetitive peak off-state voltage, (note 1)	2400-2800	V
V_{DSM}	Non-repetitive peak off-state voltage, (note 1)	2400-2800	V
V_{RRM}	Repetitive peak reverse voltage, (note 1)	2400-2800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	2500-2900	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS	
$I_{T(AV)M}$	Maximum average on-state current, T _{sink} =55°C, (r	note 2)	3790	Α
$I_{T(AV)M}$	Maximum average on-state current. T _{sink} =85°C, (note 2)		2655	Α
$I_{T(AV)M}$	Maximum average on-state current. T _{sink} =85°C, (note 3)		1405	Α
I _{T(RMS)M}	Nominal RMS on-state current, T _{sink} =25°C, (note	7410	Α	
I _{T(d.c.)}	D.C. on-state current, T _{sink} =25°C, (note 4)	6610	Α	
I _{TSM}	Peak non-repetitive surge t _p =10ms, V _m =60%V _{RRM} , (note 5)		49.5	kA
I _{TSM2}	Peak non-repetitive surge t _p =10ms, V _m ≤10V, (note 5)		55.0	kA
I ² t	I ² t capacity for fusing t _p =10ms, V _m =60%V _{RRM} , (note 5)		12.3×10 ⁶	A ² s
I ² t	I²t capacity for fusing t _p =10ms, V _{rm} ≤10V, (note 5)		15.1×10 ⁶	A ² s
		(continuous, 50Hz)	100	
(di/dt) _{cr}	Critical rate of rise of on-state current (note 6)	(repetitive, 50Hz, 60s)	200	A/µs
		(non-repetitive)	400	
V_{RGM}	Peak reverse gate voltage		5	V
P _{G(AV)}	Mean forward gate power	5	W	
P _{GM}	Peak forward gate power	40	W	
T _{j op}	Operating temperature range		-40 to +125	°C
T _{stg}	Storage temperature range		-40 to +150	°C

Notes:-

- 1) De-rating factor of 0.13% per $^{\circ}$ C is applicable for T_{j} below 25 $^{\circ}$ C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Cathode side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewave, 125°C T_i initial.
- 6) V_D =67% V_{DRM} , I_{TM} =2000A, I_{FG} =2A, t_r ≤0.5 μ s, T_{case} =125°C.



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS
V _{TM}	Maximum peak on-state voltage	-	-	1.50	I _{TM} =4000A	V
V_{TM}	Maximum peak on-state voltage	-	-	2.10	I _{TM} =8000A	V
V_{T0}	Threshold voltage	-	-	0.90		V
r⊤	Slope resistance	-	-	0.15		mΩ
(dv/dt)cr	Critical rate of rise of off-state voltage	1000	-	-	V _D =80% V _{DRM} , linear ramp, gate o/c	V/μs
I _{DRM}	Peak off-state current	-	-	250	Rated V _{DRM}	mA
I _{RRM}	Peak reverse current	-	-	250	Rated V _{RRM}	mA
V _{GT}	Gate trigger voltage	-	-	3.0	T-05°0	V
I _{GT}	Gate trigger current	-	-	300	$T_j=25$ °C $V_D=10V, I_T=3A$	mA
V_{GD}	Gate non-trigger voltage	-	-	0.25	Rated V _{DRM}	V
I _H	Holding current	-	-	1000	T _j =25°C	mA
t _{gd}	Gate-controlled turn-on delay time	-	0.7	1.5	V _D =67% V _{DRM} , I _T =2000A, di/dt=10A/μs,	μs
t _{gt}	Turn-on time	-	2.0	4.0	I _{FG} =2A, t _r =0.5µs, T _j =25°C	μs
Q _{rr}	Recovered charge	-	7000	7700		μC
Q _{ra}	Recovered charge, 50% Chord	-	4500	-	I _{TM} =4000A, t _o =2000μs, di/dt=10A/μs,	μC
Irr	Reverse recovery current	-	210	-	V _r =100V	Α
t _{rr}	Reverse recovery time	-	43	-		μs
t _q	Turn-off time	-	250	-	I _{TM} =4000A, t _p =2000μs, di/dt=10A/μs, V _r =100V, V _{dr} =80%V _{DRM} , dV _{dr} /dt=20V/μs	- µs
		-	400	-	I_{TM} =4000A, t_p =2000 μ s, di/dt =10A/ μ s, V_r =100V, V_{dr} =80% V_{DRM} , dV_{dr}/dt =200V/ μ s	
		-	-	0.008	Double side cooled	K/W
R_{thJK}	Thermal resistance, junction to heatsink	-	-	0.013	Anode side cooled	K/W
		-	-	0.020	Cathode side cooled	K/W
F	Mounting force	60	-	70	Note 2.	kN
W_t	Weight	-	1.15	-		kg

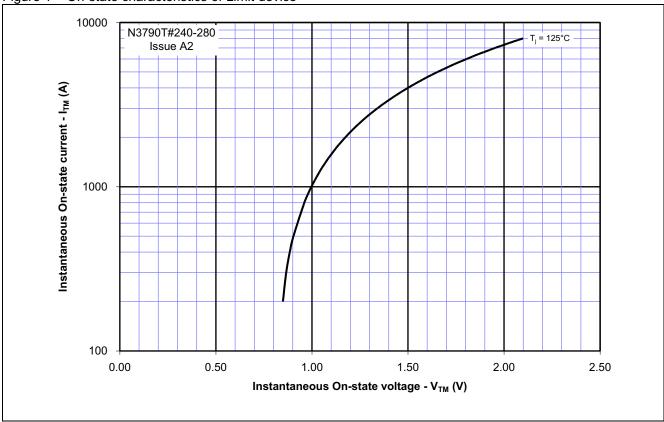
Notes:-

- 1) Unless otherwise indicated $T_j=125$ °C.
- $\overset{\circ}{2}$ For other clamp forces, please consult factory.

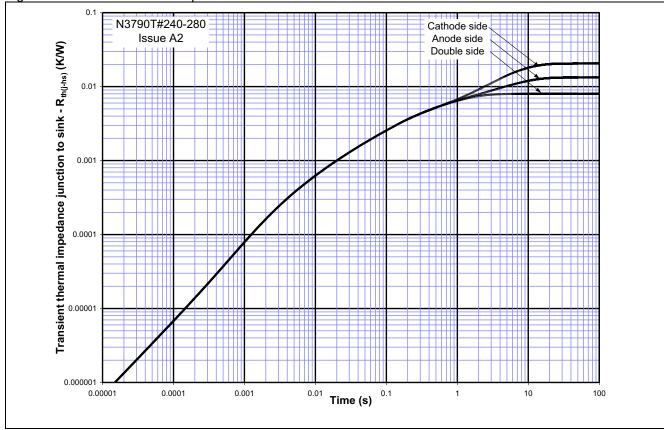


Curves

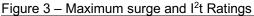


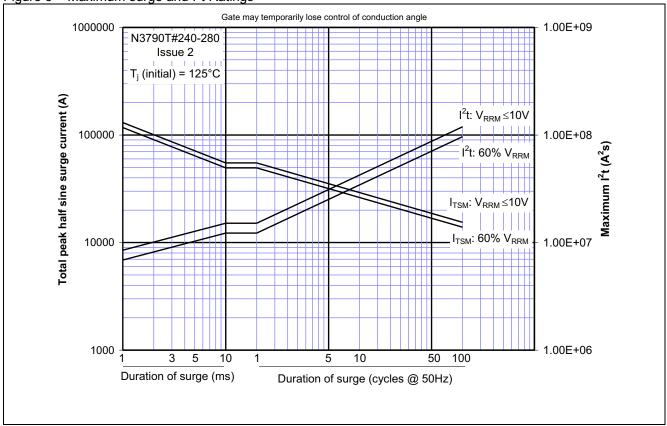






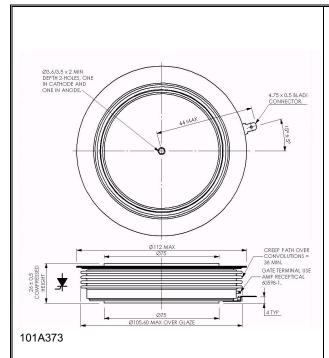


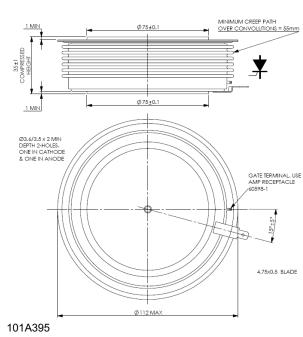






Outline Drawing & Ordering Information





Outline option TJ

Outline option TE

ORDERI	NG INFORMATION	(Please quote 10 digit code as below)		
N3790	T#	**	0	
Fixed Type Code	Fixed TJ = 26mm clamp height TE = 35mm clamp height	Voltage code V _{DRM} /100 24-28	Fixed turn-off time code	

Order code: N3790TJ280 - 2800V VDRM, VRRM, 26mm clamp height capsule.

IXYS Semiconductor GmbH

Edisonstraße 15 D-68623 Lampertheim Tel: +49 6206 503-0 Fax: +49 6206 503-627 E-mail: marcom@ixys.de



IXYS UK Westcode Ltd

Langley Park Way, Langley Park, Chippenham, Wiltshire, SN15 1GE. Tel: +44 (0)1249 444524 Fax: +44 (0)1249 659448 E-mail: sales@ixysuk.com

IXYS Corporation

1590 Buckeye Drive Milpitas CA 95035-7418 Tel: +1 (408) 457 9000 Fax: +1 (408) 496 0670 E-mail: sales@ixys.net

www.ixysuk.com

www.ixys.com

IXYS Long Beach

IXYS Long Beach, Inc 2500 Mira Mar Ave, Long Beach CA 90815

Tel: +1 (562) 296 6584 Fax: +1 (562) 296 6585

E-mail: service@ixyslongbeach.com

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors IXYS UK Westcode Ltd.

© IXYS UK Westcode Ltd.

In the interest of product improvement, IXYS UK Westcode Ltd reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.

